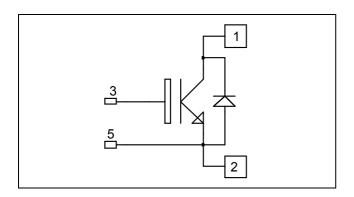
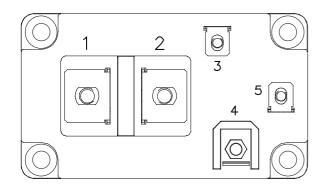


Single switch NPT IGBT Power Module





$V_{CES} = 600V$ $I_C = 360A$ @ Tc = 80°C

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- M6 connectors for power
- M4 connectors for signal
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit	
V _{CES}	Collector - Emitter Breakdown Voltage		600	V	
I _C	Continuous Collector Current	$T_C = 25^{\circ}C$	450		
	Continuous Conector Current	$T_C = 80^{\circ}C$	360	Α	
I _{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	720		
V_{GE}	Gate – Emitter Voltage		±20	V	
P _D	Maximum Power Dissipation	$T_C = 25^{\circ}C$	1560	W	
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	800A@520V		

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25^{\circ}C$			500	μA
I _{CES}	Zero Gate Voltage Concetor Current	$V_{CE} = 600 V$	$T_j = 125^{\circ}C$			1	mA
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.95	2.45	V
		$I_{\rm C} = 400 {\rm A}$ $T_{\rm j} = 125^{\circ} {\rm C}$		2.2		v	
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 6mA$		4.5	5.5	6.5	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				1200	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$			17		nF
C _{res}	Reverse Transfer Capacitance	f = 1 MHz	f = 1 MHz		1.6		m
Q _G	Gate charge	V_{GE} =15V, I _C =400A V _{CE} =300V			1		μC
T _{d(on)}	Turn-on Delay Time	Inductive Switch	hing (25°C)		150		ns
Tr	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$			72		
T _{d(off)}	Turn-off Delay Time	$I_C = 400A$			530		115
$T_{\rm f}$	Fall Time	$R_G = 8\Omega$			40		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C)			160		
T _r	Rise Time		$V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $L_{a} = 400A$		75		ns
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 400A$			550		
$T_{\rm f}$	Fall Time	$R_G = 8\Omega$			50		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$	$T_j = 125^{\circ}C$		18.6		mJ
E _{off}	Turn off Energy	$I_{\rm C} = 400 {\rm A}$ $R_{\rm G} = 8 {\rm \Omega}$	$T_j = 125^{\circ}C$		17.3		mJ
I _{sc}	Short Circuit data	$ \begin{array}{l} V_{GE} \leq \!\! 15V \ ; \ V_{Bus} = 360V \\ t_p \leq 10 \mu s \ ; \ T_j = 125^\circ C \end{array} $			1800		А

Reverse diode ratings and characteristics

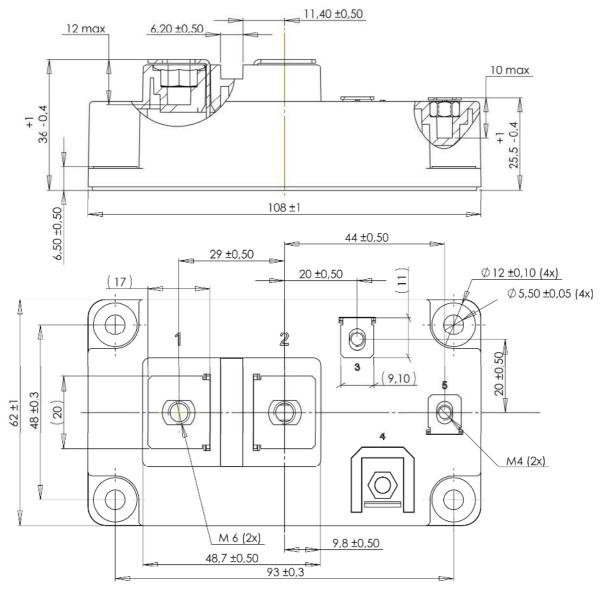
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I _{RRM}	Maximum Reverse Leakage Current	$V_R = 600V$	$T_{i} = 25^{\circ}C$ $T_{i} = 125^{\circ}C$			750 1000	μΑ
I _F	DC Forward Current		$Tc = 80^{\circ}C$		400		Α
V _F	Diode Forward Voltage	$I_{\rm F} = 400 {\rm A}$ $V_{\rm GE} = 0 {\rm V}$	$T_i = 25^{\circ}C$		1.25	1.6	V
v _F			$T_{i} = 125^{\circ}C$		1.2		v
+	Deserve Deservery Time		$T_j = 25^{\circ}C$		150		
t _{rr}	Reverse Recovery Time		$T_j = 125^{\circ}C$		250		ns
Q _{rr}	Reverse Recovery Charge	$I_{\rm F} = 400 \text{A}$ $V_{\rm R} = 300 \text{V}$ $di/dt = 4400 \text{A}/\mu \text{s}$	$T_j = 25^{\circ}C$		27		μC
Qrr			$T_{j} = 125^{\circ}C$		44		μυ
Б	Bayanga Baaayany Enangy		$T_j = 25^{\circ}C$		5.6		mJ
E _{rr}	Reverse Recovery Energy		$T_{j} = 125^{\circ}C$		9.2		1113



Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R _{thJC}	Junction to Case Thermal Resistance	IGBT			0.08	°C/W	
R _{th} JC		Diode			0.15	C/ W	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V	
TJ	Operating junction temperature range		-40		150	°C	
T _{STG}	Storage Temperature Range		-40		125		
T _C	Operating Case Temperature		-40		125		
Torque	Mounting torque	M6	3		5	N.m	
		M4	1		2	19.111	
Wt	Package Weight				350	g	

D4 Package outline (dimensions in mm)

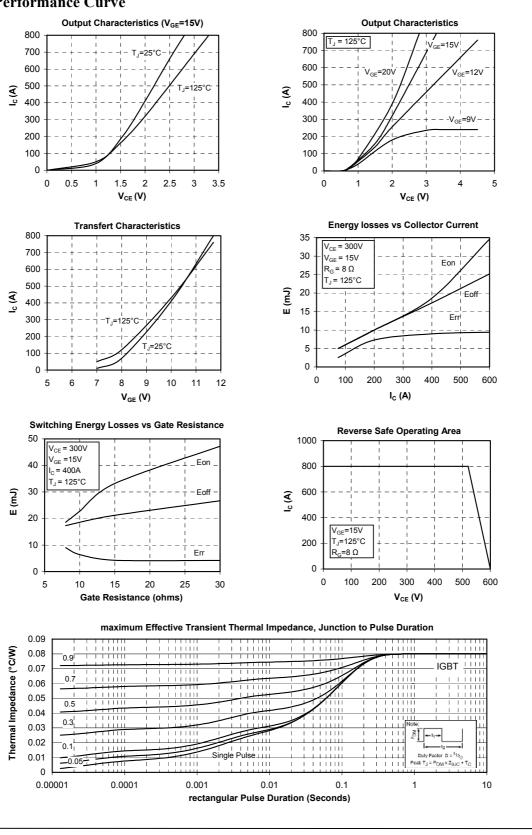


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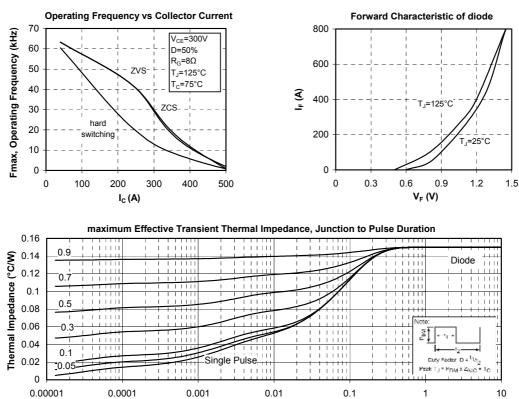
Typical Performance Curve







1



rectangular Pulse Duration (Seconds)

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